
State-of-the-Art Program on Compound Semiconductors 57 (SOTAPOCS 57)

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Table of Contents

<i>Preface</i>	<i>iii</i>
----------------	------------

**Chapter 1
Compound Semiconductor Processing**

(Invited) Preparation of GaSb Surface for Low Interfacial Trap Density MOS Capacitors	3
---	---

C. Y. Chen, W. J. Hsueh, C. M. Chang, H. M. Hsu, J. I. Chyi

Surface Metal Cleaning of GaN Surface Based on Redox Potential of Cleaning Solution	11
---	----

K. Nagao, K. Nakamura, A. Teramoto, Y. Shirai, F. Imaizumi, T. Suwa, S. Sugawa, T. Ohmi

Annealing Effects on the Electrical Activation of Si Dopants in InGaAs	23
--	----

A. G. Lind, H. L. Aldridge Jr., C. C. Bomberger, C. Hatem, J. M. O. Zide, K. S. Jones

Electrochemical Transfer Doping: A Novel Phenomenon Seen in Diamond, Gallium Nitride, and Carbon Nanotubes	29
--	----

V. Chakrapani

**Chapter 2
Compound Semiconductor Growth**

(Invited) Growth of Non-Polar Cubic GaN on Common Si	41
--	----

M. Durniak, A. Bross, D. Elsaesser, A. Chaudhuri, S. C. Lee, S. R. J. Brueck, C. Wetzel

Ag-Fe ₂ O ₃ Heterostructured Nanoparticles as Photocatalysts under Visible Light Irradiation	45
--	----

S. Liu, Y. Chen, L. Dong

The Effect of Interfacial Contamination on Antiphase Domain Boundary Formation in GaAs on Si(100)	51
<i>C. S. C. Barrett, A. G. Lind, X. Bao, Z. Ye, K. Y. Ban, P. Martin, E. Sanchez, K. S. Jones</i>	
Continuum Modelling of Silicon Diffusion and Activation in $\text{In}_{0.53}\text{Ga}_{0.47}\text{As}$	57
<i>H. L. Aldridge Jr., A. G. Lind, M. E. Law, C. Hatem, K. S. Jones</i>	
Atomic Level Simulation of Ridge Reconstruction and Passivation in GaAs Nanopillars	63
<i>T. H. Yu, C. Ratsch</i>	
(Invited) The Effect of Thermally Induced Piezoelectricity on GaN HEMT Device Characteristics	71
<i>J. Sengupta, P. McCluskey, S. Khanna</i>	
Chapter 3	
Devices 1: Optoelectronics & Photovoltaics	
(Invited) Fabrication and Applications of High-Efficiency, Lightweight, Multi-Junction Solar Cells by Epitaxial Lift-off	89
<i>V. C. Elarde, H. Miyamoto, R. Chan, C. Stender, C. Youtsey, J. G. J. Adams, A. Wibowo, R. Tatavarti, M. Osowski, N. Pan</i>	
(Invited) Advanced Photon Management in Printed High-Efficiency Multijunction Solar Cells	95
<i>X. Sheng, J. A. Rogers</i>	
(Invited) Dilute-Nitride-Antimonide Materials Grown by MOVPE for Multi-Junction Solar Cell Application	101
<i>L. J. Mawst, T. W. Kim, H. Kim, Y. Kim, K. Kim, J. J. Lee, T. F. Kuech, Z. R. Lingley, S. D. LaLumondiere, Y. Sin, W. T. Lotshaw, S. C. Moss</i>	
(Invited) InAs/InAs _{1-x} Sb _x Type-II Superlattices for High-Performance Long-Wavelength Infrared Medical Thermography	109
<i>M. Razeghi, A. Haddadi, G. Chen, R. Chevallier, A. M. Hoang</i>	
Template-directed Synthesis of Ag ₂ S-Fe ₂ O ₃ Heterostructures	117
<i>Y. Chen, S. Liu, M. Zhao, L. Yu, H. Dong, L. Dong</i>	

Chapter 4

Devices 2: HEMTs & Sensors

(Invited) The Stability of High Voltage AlGaN/GaN HEMTs <i>C. F. Huang, T. F. Chang, Y. H. Wang, Y. C. Liang</i>	127
(Invited) Plasmonic Terahertz Detectors <i>M. Shur</i>	139
Early Detection of Lung Cancer Using High Electron Mobility Transistors <i>I. Sarangadharan, C. H. Chu, C. P. Hsu, Y. L. Wang</i>	145
A Semiconductor Gas System of Healthcare for Liver Disease Detection Using Ultrathin InN-Based Sensor <i>K. W. A. Kao, C. J. Cheng, S. Gwo, J. A. Yeh</i>	151
Dilute Hydrogen Sulfide Sensing Characteristics of a Pt/GaN Schottky Diode <i>J. F. Xiao, C. P. Hsu, Y. L. Wang</i>	159
Detection of HIV-1 RT Protein Using AlGaN/GaN High Electron Mobility Transistors <i>C. H. Chu, C. P. Hsu, Y. L. Wang</i>	163

Chapter 5

Poster Session

The Photoluminescence Properties of CuInS ₂ and AgInS ₂ Nanocrystals Synthesized in Aqueous Solutions <i>L. Borkovska, A. Romanyuk, V. Strelchuk, Y. Polishchuk, V. Kladko, O. Stroyuk, A. Raevskaya, T. Kryshtab</i>	171
Metallization Reliability and Defectivity in Compound Semiconductors <i>S. Kilgore</i>	181
Author Index	189